NP0G3D2

Silicon PNP epitaxial planar transistor (Tr1) Silicon NPN epitaxial planar transistor (Tr2)

For digital circuits

■ Features

- Two elements incorporated into one package
- Suitable for high density package and downsizing of the equipment
- Automatic insertion with the taping is possible

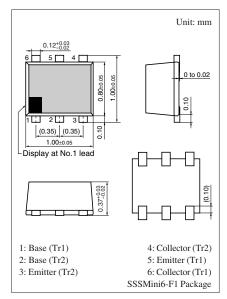
■ Basic Part Number of Element

• UNR31AT × UNR32AL

■ Absolute Maximum Ratings $T_a = 25$ °C

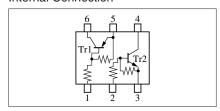
	Parameter	Symbol	Rating	Unit	
Tr1	Collector to base voltage	V_{CBO}	-50	V	
	Collector to emitter voltage	V _{CEO}	-50	V	
	Collector current	I_C	-80	mA	
Tr2	Collector to base voltage	V_{CBO}	50	V	
	Collector to emitter voltage	V_{CEO}	50	V	
	Collector current	I_C	80	mA	
Overall	Total power dissipation *	P_{T}	125	mW	
	Junction temperature	T _j	125	°C	
	Storage temperature	T_{stg}	-55 to +125	°C	

Note) *: Measuring on substrate at 17 mm \times 10 mm \times 1 mm



Marking Symbol: 3B

Internal Connection



\blacksquare Electrical Characteristics $T_a = 25^{\circ}C \pm 3^{\circ}C$

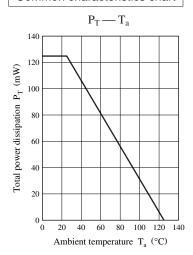
• Tr1

Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Collector to base voltage	V_{CBO}	$I_{\rm C} = -10 \; \mu \text{A}, \; I_{\rm E} = 0$	-50			V
Collector to emitter voltage	V _{CEO}	$I_{\rm C} = -2 \text{ mA}, I_{\rm B} = 0$	-50			V
Collector cutoff current	I_{CBO}	$V_{CB} = -50 \text{ V}, I_E = 0$			- 0.1	μΑ
	I _{CEO}	$V_{CE} = -50 \text{ V}, I_{B} = 0$			- 0.5	
Emitter cutoff current	I_{EBO}	$V_{EB} = -6 \text{ V}, I_C = 0$			- 0.2	mA
Forward current transfer ratio	h _{FE}	$V_{CE} = -10 \text{ V}, I_{C} = -5 \text{ mA}$	80		400	_
Collector to emitter saturation voltage	V _{CE(sat)}	$I_C = -10 \text{ mA}, I_B = -0.3 \text{ mA}$			- 0.25	V
High level output voltage	V _{OH}	$V_{CC} = -5 \text{ V}, V_B = -0.5 \text{ V}, R_L = 1 \text{ k}\Omega$	-4.9			V
Low level output voltage	V _{OL}	$V_{CC} = -5 \text{ V}, V_B = -2.5 \text{ V}, R_L = 1 \text{ k}\Omega$			- 0.2	V
Input resistance	R ₁		-30%	22	+30%	kΩ
Resistance ratio	R ₁ / R ₂			0.47		_
Gain bandwidth product	f_T	$V_{CB} = -10 \text{ V}, I_E = 1 \text{ mA}, f = 200 \text{ MHz}$		80		MHz

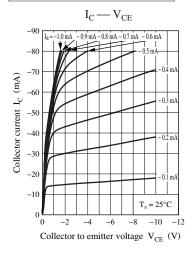
• Tr2

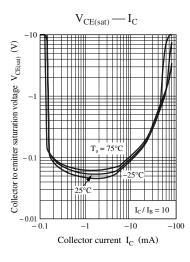
Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Collector to base voltage	V_{CBO}	$I_C = 10 \ \mu A, \ I_E = 0$	50			V
Collector to emitter voltage	V _{CEO}	$I_C = 2 \text{ mA}, I_B = 0$	50			V
Collector cutoff current	I_{CBO}	$V_{CB} = 50 \text{ V}, I_E = 0$			0.1	μΑ
	I _{CEO}	$V_{CE} = 50 \text{ V}, I_B = 0$			0.5	
Emitter cutoff current	I_{EBO}	$V_{EB} = 6 \text{ V}, I_{C} = 0$			2.0	mA
Forward current transfer ratio	h _{FE}	$V_{CE} = 10 \text{ V}, I_{C} = 5 \text{ mA}$	20			_
Collector to emitter saturation voltage	V _{CE(sat)}	$I_C = 10 \text{ mA}, I_B = 0.3 \text{ mA}$			0.25	V
High level output voltage	V _{OH}	$V_{CC} = 5 \text{ V}, V_B = 0.5 \text{ V}, R_L = 1 \text{ k}\Omega$	4.9			V
Low level output voltage	V _{OL}	$V_{CC} = 5 \text{ V}, V_{B} = 2.5 \text{ V}, R_{L} = 1 \text{ k}\Omega$			0.2	V
Input resistance	R_1		-30%	4.7	+30%	kΩ
Resistance ratio	R ₁ / R ₂		0.8	1.0	1.2	_
Gain bandwidth product	f_T	$V_{CB} = 10 \text{ V}, I_E = -2 \text{ mA}, f = 200 \text{ MHz}$		150		MHz

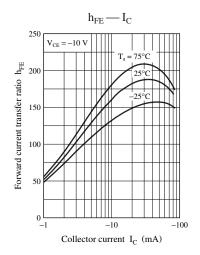
Common characteristics chart

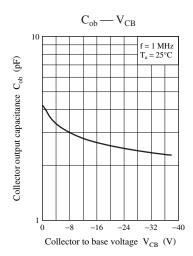


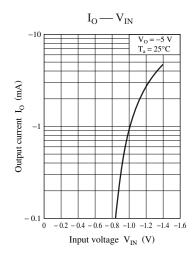
Characteristics charts of Tr1

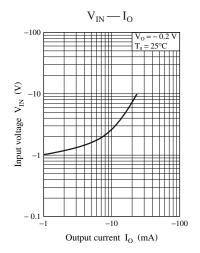






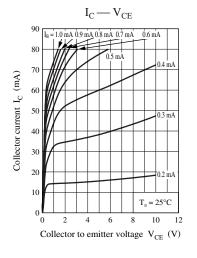


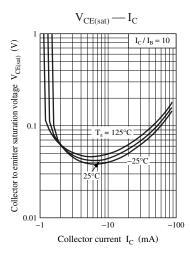


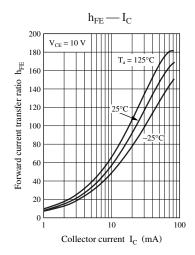


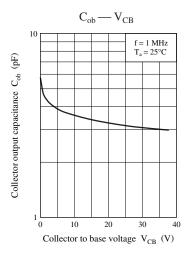
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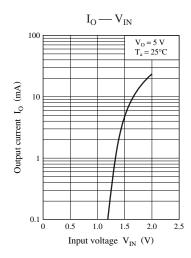
Characteristics charts of Tr2

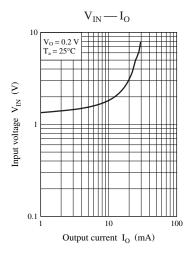












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